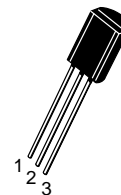
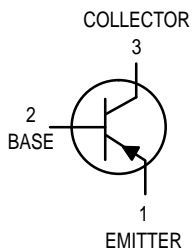


One Watt Amplifier Transistors

PNP Silicon

BDB02C,D



CASE 29-05, STYLE 1
TO-92 (TO-226AE)

MAXIMUM RATINGS

Rating	Symbol	BDB02C	BDB02D	Unit
Collector–Emitter Voltage	V_{CEO}	–80	–100	Vdc
Collector–Base Voltage	V_{CES}	–80	–100	Vdc
Emitter–Base Voltage	V_{EBO}	–5.0		Vdc
Collector Current — Continuous	I_C	–0.5		Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 8.0		Watt mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	2.5 20		Watt mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	50	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Voltage ($I_C = -10\text{ mA}$, $I_B = 0$)	BDB02C BDB02D	$V_{(BR)CEO}$	–80 –100	— —	Vdc
Collector Cutoff Current ($V_{CB} = -80\text{ V}$, $I_E = 0$) ($V_{CB} = -100\text{ V}$, $I_E = 0$)	BDB02C BDB02D	I_{CBO}	— —	–0.1 –0.1	μAdc
Emitter Cutoff Current ($I_C = 0$, $V_{EB} = -5.0\text{ V}$)		I_{EBO}	—	–100	nAdc

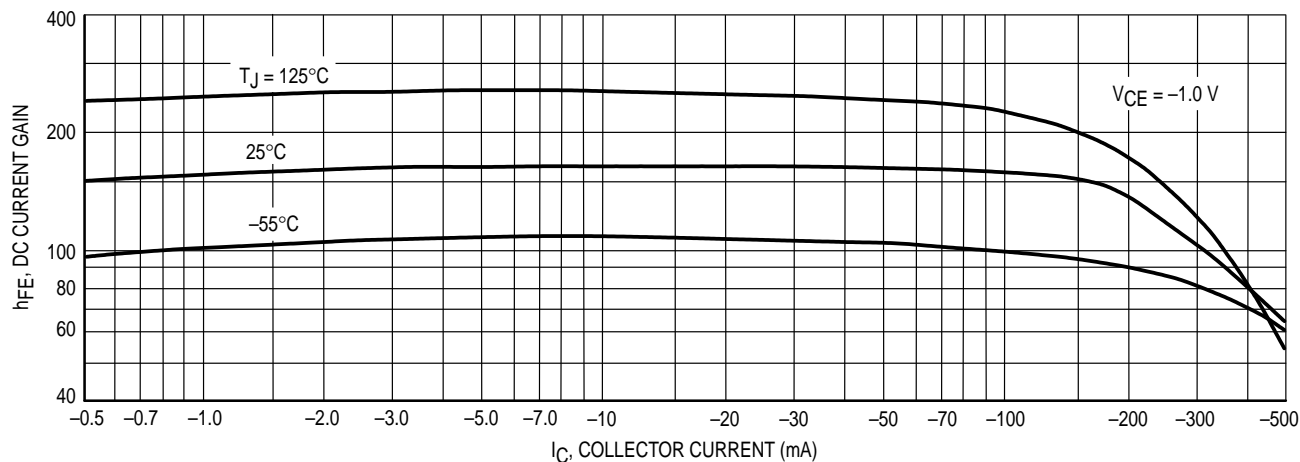
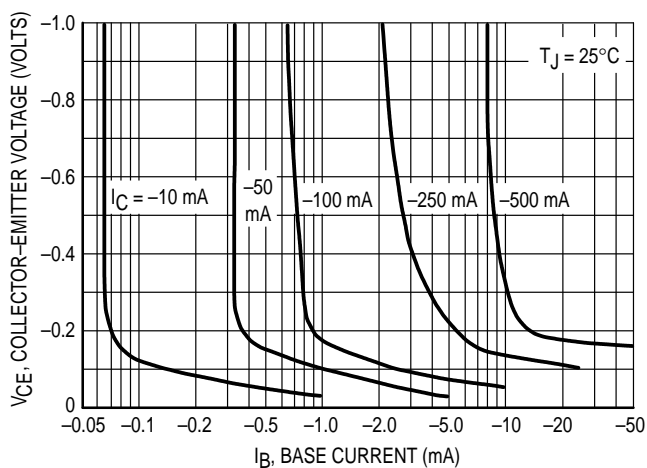
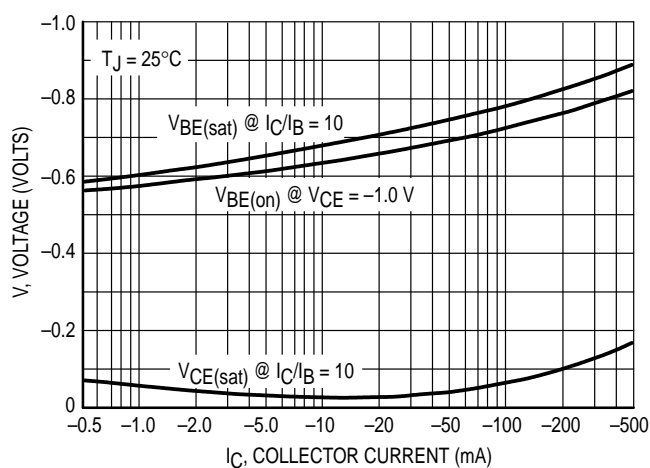
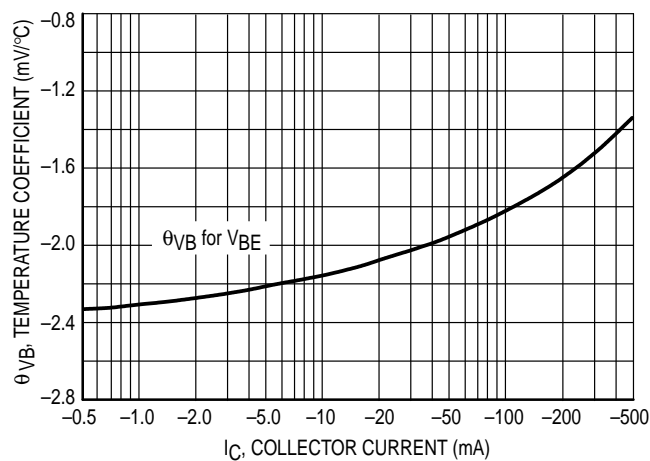
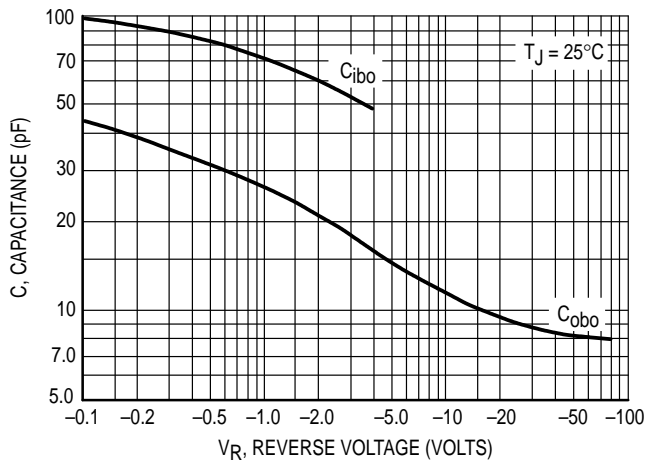
ON CHARACTERISTICS

DC Current Gain ($I_C = -100\text{ mA}$, $V_{CE} = -1.0\text{ V}$) ($I_C = -500\text{ mA}$, $V_{CE} = -2.0\text{ V}$)	h_{FE}	40 25	400 —	—
Collector–Emitter Saturation Voltage ⁽¹⁾ ($I_C = -1000\text{ mA}$, $I_B = -100\text{ mA}$)	$V_{CE(sat)}$	—	–0.7	Vdc
Collector–Emitter On Voltage ⁽¹⁾ ($I_C = -1000\text{ mA}$, $V_{CE} = -1.0\text{ V}$)	$V_{BE(on)}$	—	–1.2	Vdc

DYNAMIC CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = -200\text{ mA}$, $V_{CE} = -5.0\text{ V}$, $f = 20\text{ MHz}$)	f_T	50	—	MHz
Output Capacitance ($V_{CB} = -10\text{ V}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{ob}	—	30	pF

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle 2.0%.


Figure 1. DC Current Gain

Figure 2. Collector Saturation Region

Figure 3. On Voltages

Figure 4. Base-Emitter Temperature Coefficient

Figure 5. Capacitance

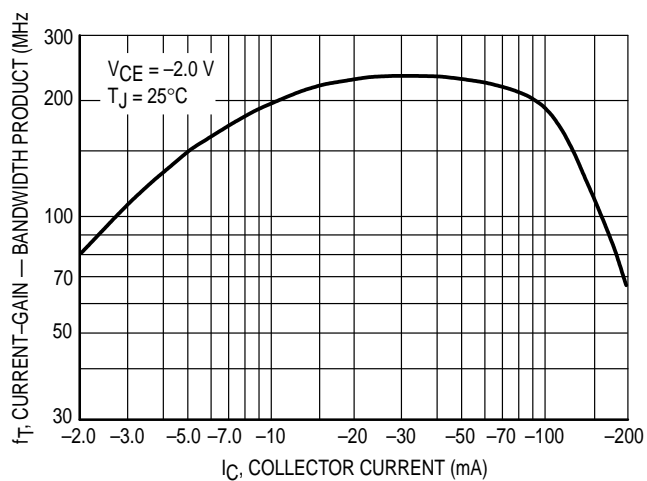


Figure 6. Current-Gain — Bandwidth Product

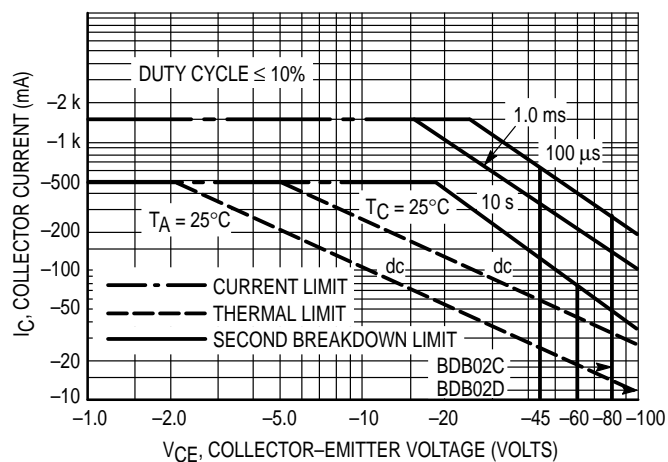
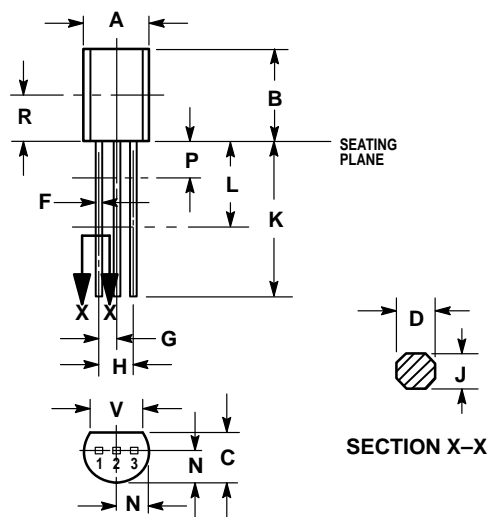


Figure 7. Active Region — Safe Operating Area

PACKAGE DIMENSIONS



NOTES:


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.135	—	3.43	—
V	0.135	—	3.43	—

STYLE 1:

1. PIN 1. EMITTER
2. BASE
3. COLLECTOR

**CASE 029-05
(TO-226AE)
ISSUE AD**

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